






MT47H512M4EB-3:C

Part Number:	MT47H512M4EB-3:C
Manufacturer/Brand:	Micron Technology
Product description	IC DRAM 2G PARALLEL 60FBGA
Datasheets:	 MT47H512M4EB-3:C.pdf
RoHs Status	 Lead free / RoHS Compliant
Stock Condition	2942 pcs stock
Ship From	Hong Kong
Shipment Way	DHL/Fedex/TNT/UPS/EMS

REQUEST FOR QUOTATION

Image may be representation. See specifications for product details.













Specifications of MT47H512M4EB-3:C

PART NUMBER	MT47H512M4EB-3:C
MANUFACTURER	Micron Technology
DESCRIPTION	IC DRAM 2G PARALLEL 60FBGA
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
QUANTITY AVAILABLE	2942 pcs
DATA SHEET	 MT47H512M4EB-3:C.pdf
WRITE CYCLE TIME - WORD, PAGE	15ns
VOLTAGE - SUPPLY	1.7 V ~ 1.9 V
TECHNOLOGY	SDRAM - DDR2
SUPPLIER DEVICE PACKAGE	60-FBGA (9x11.5)
SERIES	-
PACKAGING	Tray
PACKAGE / CASE	60-TFBGA
OPERATING TEMPERATURE	0°C ~ 85°C (TC)
MOUNTING TYPE	Surface Mount
MOISTURE SENSITIVITY LEVEL (MSL)	3 (168 Hours)
MEMORY TYPE	Volatile
MEMORY SIZE	2Gb (512M x 4)
MEMORY INTERFACE	Parallel
MEMORY FORMAT	DRAM
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DETAILED DESCRIPTION	SDRAM - DDR2 Memory IC 2Gb (512M x 4) Parallel 333MHz 450ps 60-FBGA (9x11.5)
CLOCK FREQUENCY	333MHz
BASE PART NUMBER	MT47H512M4
ACCESS TIME	450ps

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